

Voltage Controlled Crystal Oscillator

3.3V, LVCMOS

Technical Data

S1300 / S1309 / ST1300 / ST1309 Series





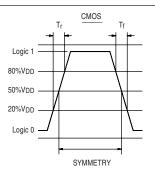
Description

A 3.3V, voltage controlled crystal oscillator with output logic levels compatible with LVCMOS and LVTTL logic families. The series is designed with excellent Jitter characteristics which makes it ideal for use in Telecom and Datacom applications. True SMD DIL versions for IR reflow are available, select option "S" in part number builder. See separate data sheet for SMD package dimensions.

Applications & Features

- Phase-Locked Loop (PLL) Clock and Data Recovery, Frequency Transaltion, Frequency Synthesis apps in Video, Video Compression, Telephony, and LAN/WAN Data Communication
- 3.3 Volt operations
- LVCMOS / LVTTL compatible
- 3.5ps max RMS period jitter
- Wide range of performance options:
 ±50 to ±100 ppm APR*
 ±20 to ±50 ppm Frequency Stability
- Tri-State option
- True SMD for IR reflow available

Output Waveform



Frequency Range:	1.5 MHz to 28.6363 MHz
Frequency Stability:	± 20 , ± 25 or ± 50 ppm over all conditions: operating temperature, voltage change, load change, calibration tolerance, shock and vibration, with $V_C=1.65V$
Aging @ 25°C:	± 3ppm max per year, ±10ppm max for 10 years
Temperature Range:	
Operating:	0 to +70°C or -40 to +85°C
Storage:	-55 to +125°C
Supply Voltage:	
Recommended Operating:	$3.3V \pm 10\%$

10mA typ, 15mA max

Supply Current: Output Drive:

Pull Characteristics:

Input Impedance (pin 1): $50K\Omega$ min Frequency Response (-3dB): 10 kHz min

Pullability: ±50, ±70, ±100ppm APR* min

Control Voltage: 0.3 to 3.0V

Transfer Function: Frequency Increases when Control Voltage Increases

Linearity: 5 or 10% max Center Control Voltage: 1.65V

Mechanical:

Shock: MIL-STD-883, Method 2002, Condition B
Solderability: MIL-STD-883, Method 2003
Terminal Strength: MIL-STD-883, Method 2004, Condition B2
Vibration: MIL-STD-883, Method 2007, Condition A
Solvent Resistance: MIL-STD-202, Method 215
Resistance to Soldering Heat: MIL-STD-202, Method 210, Conditions A, B or C
(1 or J for Gull Wing)

Environmental:

Gross Leak Test: MIL-STD-883C, Method 1014, Condition C
Fine Leak Test: MIL-STD-883C, Method 1014, Condition A2
Thermal Shock: MIL-STD-883C, Method 1011, Condition A
Moisture Resistance: MIL-STD-883C, Method 1004

* APR = (VCXO Pull relative to specified Output Frequency) – (VCXO Frequency Stability) NOTE: APR is inclusive of 10 Years Aging

DS-126 REV E



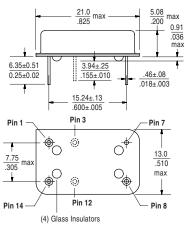
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Package Details



Pin Function:

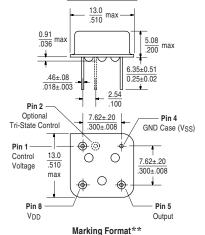
Pin 1: Control Voltage Pin 3: Tri-State control (optional) Pin 7: GND/Case (VSS) Pin 8: OUTPUT Pin 12: N/C (optional) Pin 14: +3.3VDC (VDD)

Marking Format**

Includes Date Code, Frequency & Part Number



HALF SIZE PACKAGE



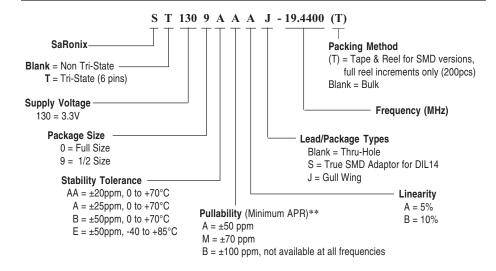
Includes Date Code, Frequency & Part Number



**Exact location of items may vary

Scale: None (Dimensions in mm/inches)

Part Numbering Guide



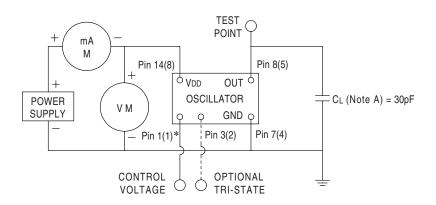
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NOTE: APR is inclusive of 10 Years Aging

Tri-State Logic Table

Pin 3(2) Input	Pin 8(5) Output
Logic 1 or NC	Oscillation
Logic 0 or GND	High Impedance

Required Input Levels on Pin 3(2): Logic 1 = 0.7 V_{DD} min Logic 0 = 0.3 V_{DD} max

Test Circuit



NOTE A: C_L includes probe and fixture capacitance
* Items in brackets() represent Half Size model

All specifications are subject to change without notice.

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True SMD Adaptor

Technical Data 20.32 12.70 10.82 .500 .426 13.4 .527 15.24 .600 RECOMMENDED LAND PATTERN